



# PJD60R390E / PJP60R390E / PJF60R390E

## 600V N-Channel Super Junction MOSFET

Voltage

600 V

Current

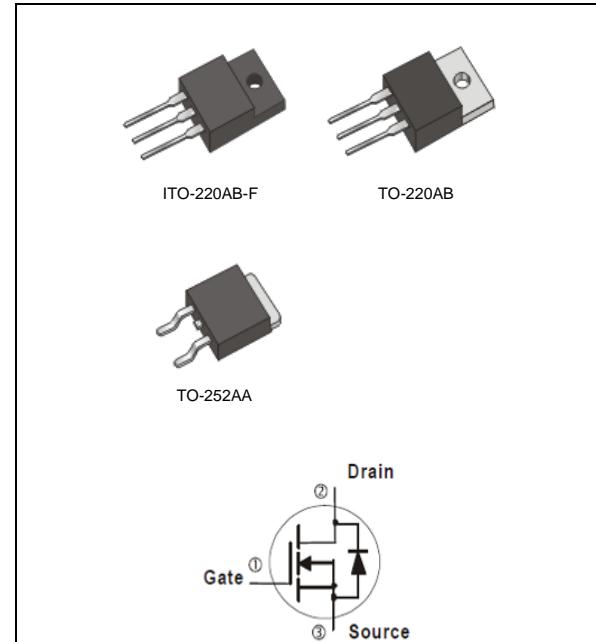
11 A

### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@3.8A<0.39\Omega$
- Fast switching speed
- Low on-resistance
- Low Noise
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : TO-252AA, TO-220AB, ITO-220AB-F
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TO-220AB	ITO-220AB-F	TO-252AA	UNITS		
Drain-Source Voltage	$V_{DS}$	600	$\pm 20$		V		
Gate-Source Voltage	$V_{GS}$						
Continuous Drain Current <sup>(Note 4)</sup>	$T_C=25^\circ C$	11	7.5		A		
	$T_C=100^\circ C$						
Pulsed Drain Current <sup>(Note 1)</sup>	$I_{DM}$	22					
Power Dissipation <sup>(Note 3)</sup>	$T_C=25^\circ C$	124	53	124	W		
	$T_C=100^\circ C$						
Continuous Drain Current <sup>(Note 4)</sup>	$T_A=25^\circ C$	1.5	1.2		A		
	$T_A=70^\circ C$						
Power Dissipation	$T_A=25^\circ C$	2	1.04	2	W		
	$T_A=70^\circ C$						
Single Pulse Avalanche Energy <sup>(Note 5)</sup>	$E_{AS}$	162			mJ		
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150			°C		
Typical Thermal Resistance <sup>(Note 4,5)</sup>	$R_{\theta JC}$	1	2.36	1	°C/W		
	$R_{\theta JA}$	62.5	120	62.5			

- Limited only By Maximum Junction Temperature



## PJD60R390E / PJP60R390E / PJF60R390E

**Electrical Characteristics** ( $T_A=25^\circ C$  unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	3.1	4	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=3.8A$	-	0.35	0.39	$\Omega$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=600V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
Diode Forward Voltage	$V_{SD}$	$I_S=11A, V_{GS}=0V$	-	0.95	1.5	V
Transconductance	$G_{FS}$	$V_{DS}=10V, I_D=5.5A$	-	6	-	S
<b>Dynamic</b> (Note 7)						
Total Gate Charge	$Q_g$	$V_{DS}=300V, I_D=11A,$ $V_{GS}=10V$ (Note 2,3)	-	32	-	nC
Gate-Source Charge	$Q_{gs}$		-	4.6	-	
Gate-Drain Charge	$Q_{gd}$		-	17	-	
Gate Input Resistance	$R_g$	$f = 1MHz$	-	7.7	-	$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1MHz$	-	531	-	pF
Output Capacitance	$C_{oss}$		-	547	-	
Reverse Transfer Capacitance	$C_{rss}$		-	69	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V, I_D=5.5A,$ $R_G=10\Omega$ (Note 2,3)	-	12	-	ns
Turn-On Rise Time	$t_r$		-	27	-	
Turn-Off Delay Time	$t_{d(off)}$		-	86	-	
Turn-Off Fall Time	$t_f$		-	27	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	11	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	---	-	-	22	
Reverse Recovery Time	$trr$	$V_{GS}=0V, I_S=11A$ $dI_F/dt=100A/us$ (Note 2)	-	389	-	ns
Reverse Recovery Charge	$Qrr$		-	5.43	-	uC

NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ C$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ C$ .
4. The maximum current rating is package limited.
5. TO-252AA mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6.  $L=100mH, I_{AS}=1.8A, V_{DD}=50V, R_G=25\Omega$ , Starting  $T_J=25^\circ C$ .
7. Guaranteed by design, not subject to production testing.



## PJD60R390E / PJP60R390E / PJF60R390E

### TYPICAL CHARACTERISTIC CURVES

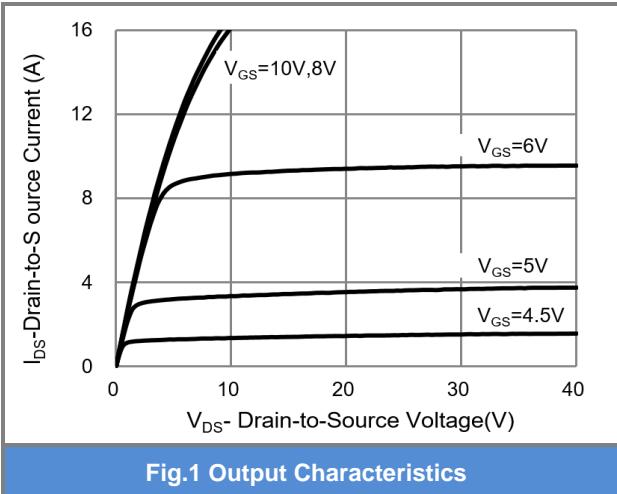


Fig.1 Output Characteristics

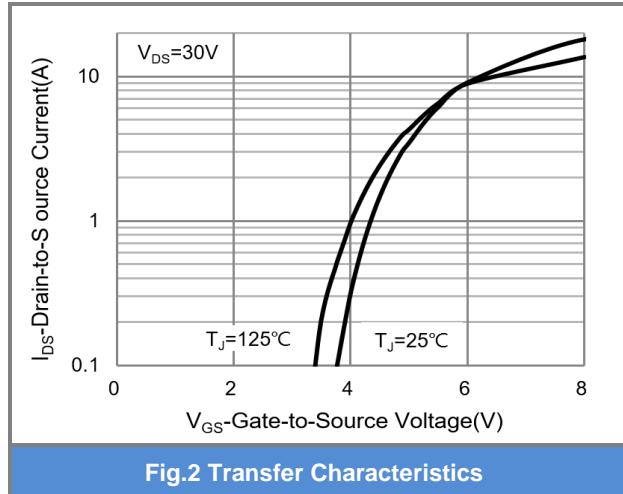


Fig.2 Transfer Characteristics

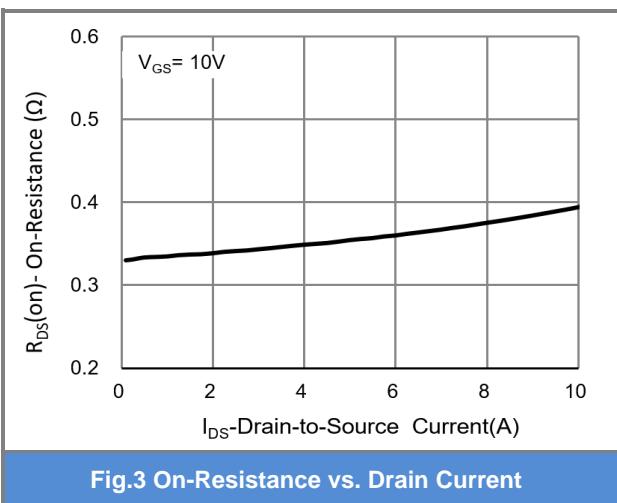


Fig.3 On-Resistance vs. Drain Current

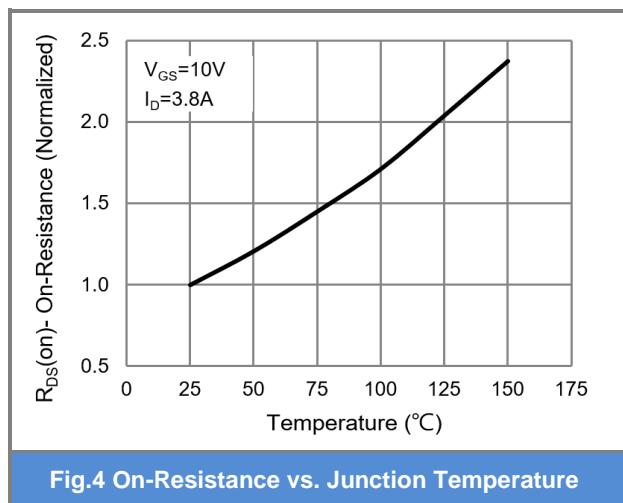


Fig.4 On-Resistance vs. Junction Temperature

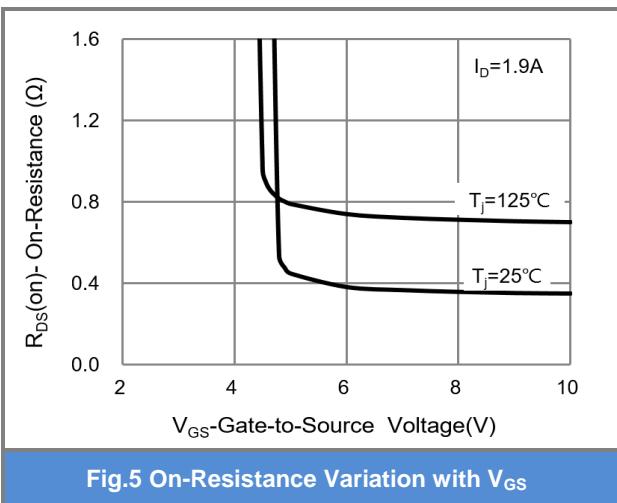


Fig.5 On-Resistance Variation with  $V_{GS}$

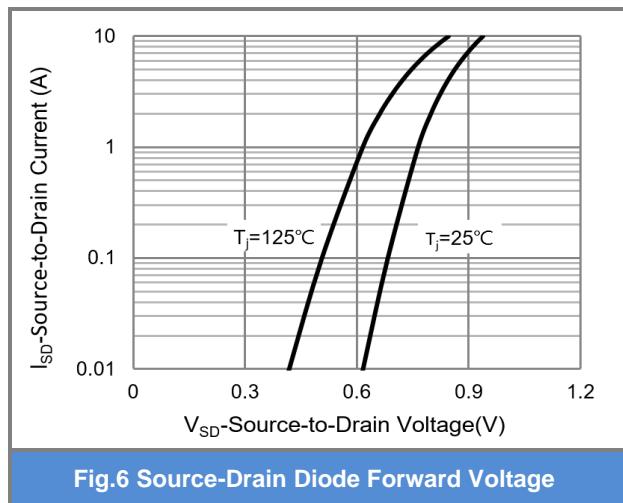


Fig.6 Source-Drain Diode Forward Voltage



## PJD60R390E / PJP60R390E / PJF60R390E

### TYPICAL CHARACTERISTIC CURVES

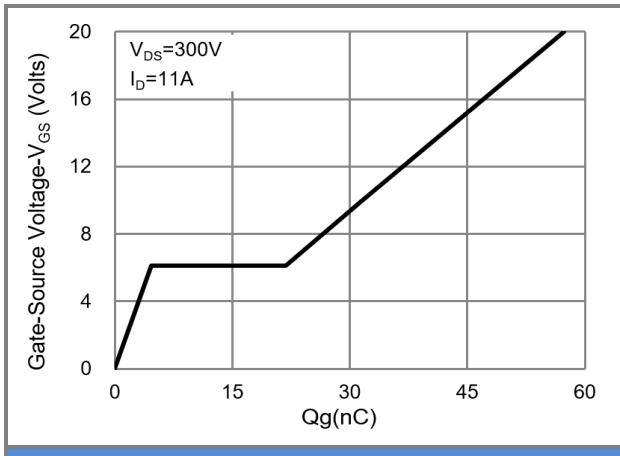


Fig.7 Gate-Charge Characteristics

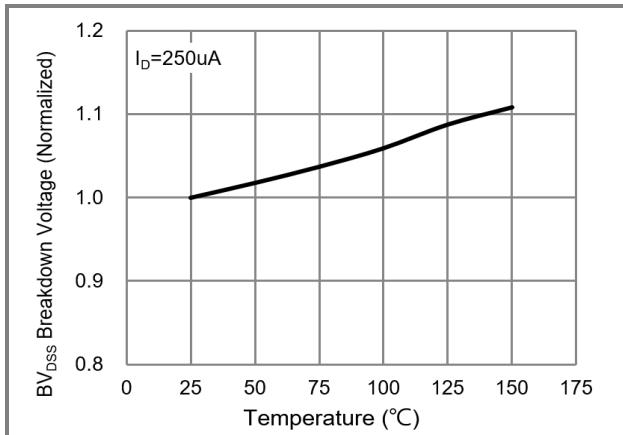


Fig.8 Breakdown Voltage Variation vs. Temperature

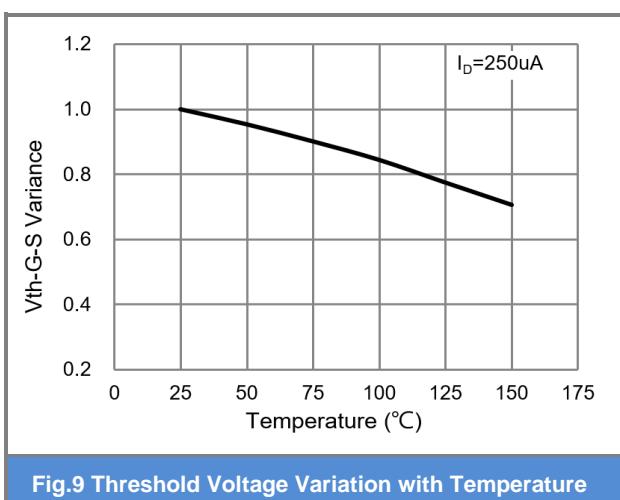


Fig.9 Threshold Voltage Variation with Temperature

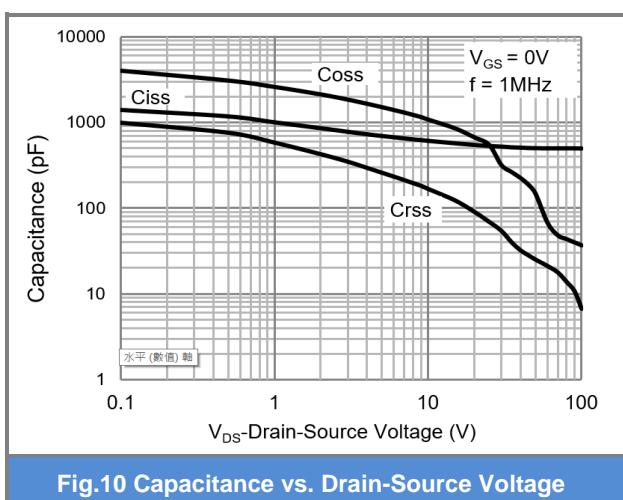


Fig.10 Capacitance vs. Drain-Source Voltage

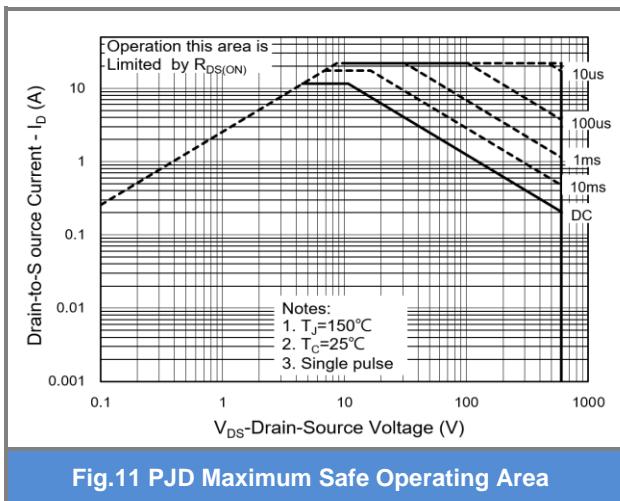


Fig.11 PJD Maximum Safe Operating Area

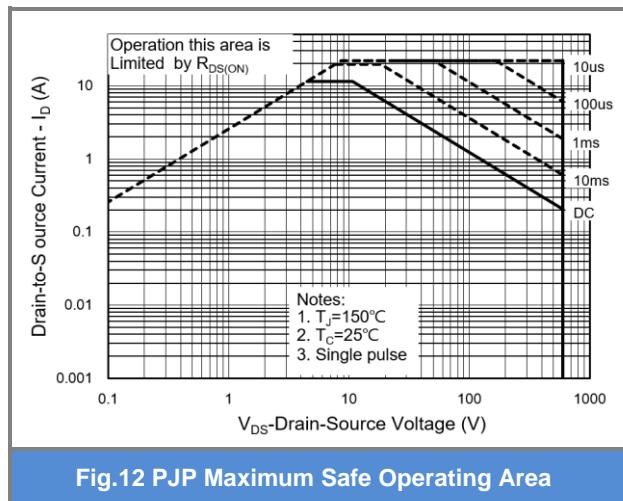


Fig.12 PJP Maximum Safe Operating Area



## PJD60R390E / PJP60R390E / PJF60R390E

### TYPICAL CHARACTERISTIC CURVES

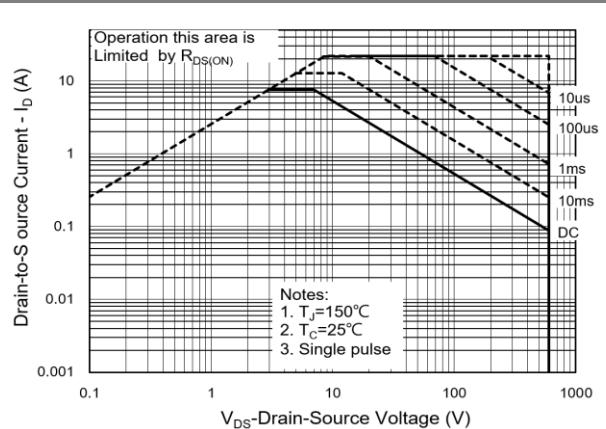


Fig.13 PJF Maximum Safe Operating Area

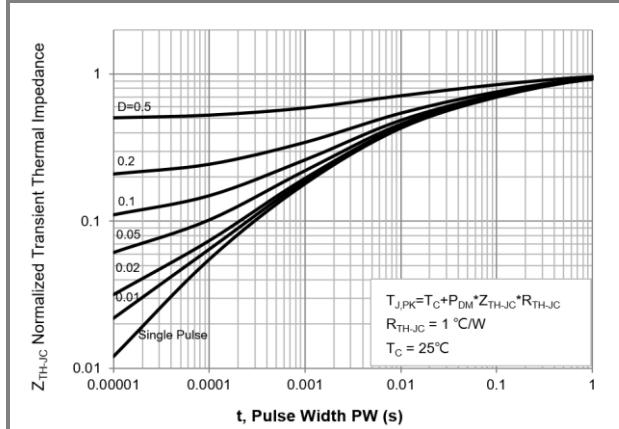


Fig.14 PJD Normalized Transient Thermal Impedance

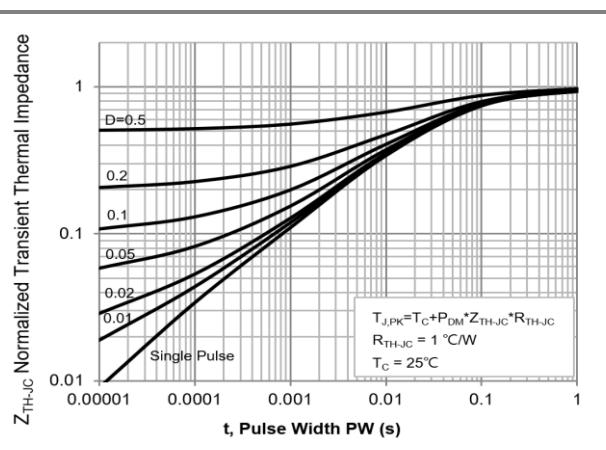


Fig.15 PJP Normalized Transient Thermal Impedance

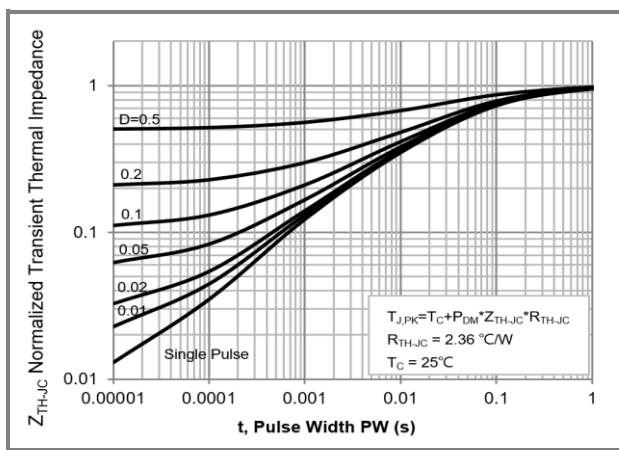


Fig.16 PJF Normalized Transient Thermal Impedance

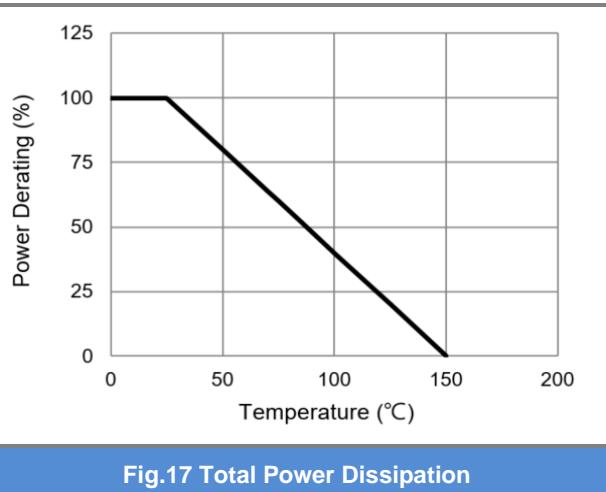
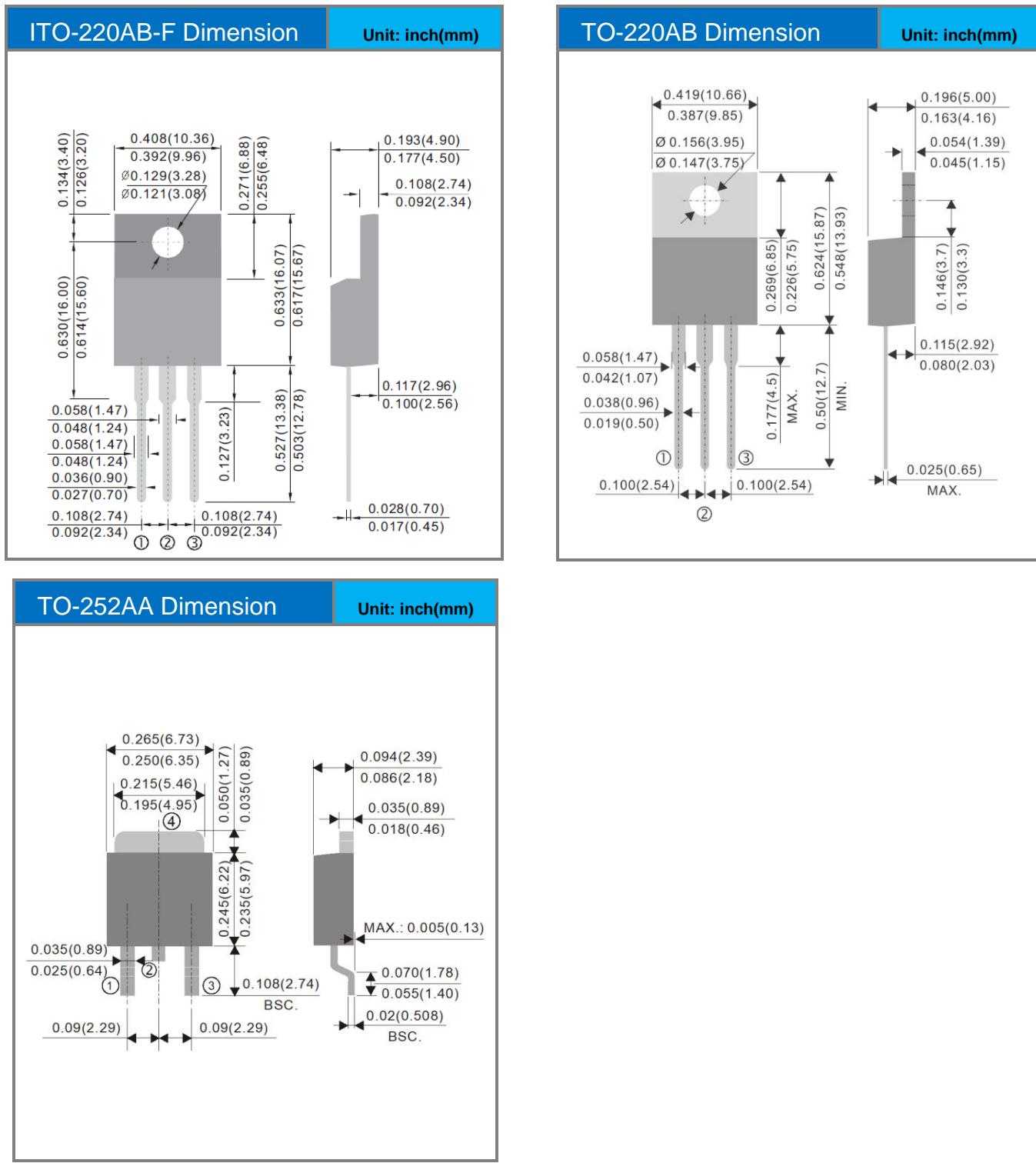


Fig.17 Total Power Dissipation



## PJD60R390E / PJP60R390E / PJF60R390E

### Packaging Information





## **PJD60R390E / PJP60R390E / PJF60R390E**

### **Part No Packing Code Version**

<b>Part No Packing Code</b>	<b>Package Type</b>	<b>Packing Type</b>	<b>Marking</b>	<b>Version</b>
PJD60R390E_L2_00001	TO-252AA	3,000pcs / 13" reel	60R390E	Halogen free
PJP60R390E_T0_00001	TO-220AB	50pcs / Tube	60R390E	Halogen free
PJF60R390E_T0_00001	ITO-220AB-F	50pcs / Tube	60R390E	Halogen free



## **PJD60R390E / PJP60R390E / PJF60R390E**

### **Disclaimer**

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.